ACNU-3410

3 Amp Gate Drive Optocoupler in 11-mm SSO-8 Package with 100 kV/µs Noise Immunity

Data Sheet

Description

The Avago Technologies® ACNU-3410 is a 3A gate drive optocoupler device in the 11-mm SSO-8 package designed for high voltage, space-constrained industrial applications, including motor drives and solar inverters. This package platform features wide 11-mm creepage and 10.5-mm clearance, high insulation voltage of V_{IORM}=1414V_{PEAK} and a compact package footprint, 40 percent smaller than the 400-mil DIP-8 package. The ACNU-3410 has common mode transient immunity (CMTI) greater than 100 kV/µs and a propagation delay faster than 150 ns, enabling high frequency switching to improve efficiency in driving IGBT and SiC/GaN MOSFET.

CAUTION Take normal static precautions in handling and assembly of this component to prevent damage, degradation, or both that might be induced by ESD. The components featured in this data sheet are not to be used in military or aerospace applications or environments.

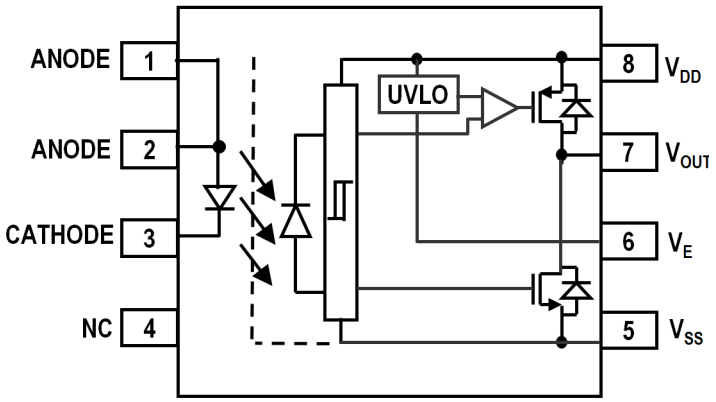
Features

- 3.0A maximum peak output current
- 11-mm creepage and 10.5-mm clearance
- Rail-to-rail output voltage
- UVLO with V_E reference for negative power supply
- 150 ns maximum propagation delay
- 90 ns maximum propagation delay difference
- LED current input with hysteresis
- 100 kV/µs minimum Common Mode Rejection (CMR) at V_{CM} = 1500 V
- I_{DD} = 5.0 mA maximum supply current
- Under Voltage Lock-Out Protection (UVLO) with Hysteresis
- Wide operating V_{DD} range: 15V to 30V
- Industrial temperature range: –40°C to 110°C
- Pending safety approvals:
  - UL Recognized 5000 V_{RMS} for 1min.
  - CSA
  - IEC/EN/DIN EN 60747-5-5 V_{IORM} = 1414 V_{peak}

Applications

- IGBT/MOSFET gate drives
- AC and brushless DC motor drives
- Renewable energy inverters
- Industrial inverters
- Switching power supplies

Figure 1 Functional Diagram



Design Notes: A 1-µF bypass capacitor must be connected between pins V_{DD} and V_{SS}.

Table 1 Truth Table – ACNU-3410

LED	V_{DD} – V_{SS} "POSITIVE GOING" (i.e., TURN-ON)	V_{DD} – V_{SS} "NEGATIVE GOING" (i.e., TURN-OFF)	VO
OFF	0 V to 30 V	0 V to 30 V	LOW
ON	0 V to 11.9 V	0 V to 10.9 V	LOW
ON	11.9 V - to 13.2 V	10.9 V to 12.2 V	TRANSITION
ON	13.2 V – to 30 V	12.2 V to 30V	HIGH

Ordering Information

ACNU-3410 is UL Recognized with 5000 V_{RMS} for 1 minute per UL1577.

Table 2 Ordering Information

Part Number	Option	Package	Tape and Reel	IEC/EN/DIN EN 60747-5-5	Quantity
	RoHS Compliant				
ACNU-3410	-000E	11-mm SSO8		X	80 per tube
	-500E		X	X	1000 per reel

To order, choose a part number from the part number column and combine with the desired option from the option column to form an order entry.

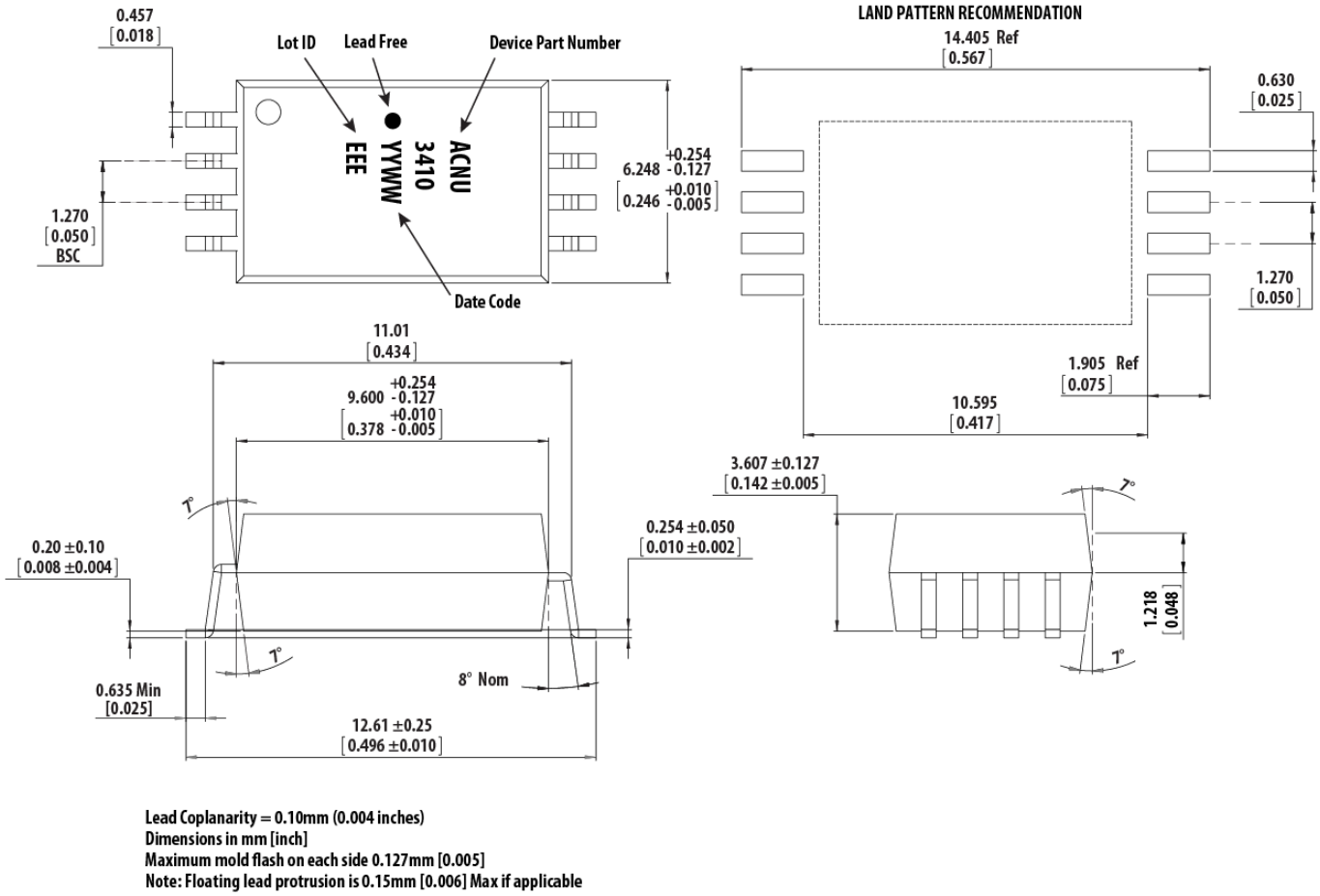
Example:

ACNU-3410-500E to order the product in tape and reel packaging with IEC/EN/DIN EN 60747-5-5 safety approval in RoHS compliant.

Option data sheets are available. Contact your Avago® sales representative or authorized distributor for information.

Package Outline Drawings

Figure 2 ACNU-3410 Outline Drawing (11-mm SSO8 Package)



Lead Coplanarity = 0.10mm (0.004 inches)
Dimensions in mm [inch]
Maximum mold flash on each side 0.127mm [0.005]
Note: Floating lead protrusion is 0.15mm [0.006] Max if applicable

Recommended Pb-Free IR Profile

Recommended reflow condition as per JEDEC Standard, J-STD-020 (latest revision). Non- Halide Flux should be used.

Regulatory Information

The ACNU-3410 is pending approval by the following organizations.

UL	Recognized under UL 1577, component recognition program up to V_{ISO} = 5000 V_{RMS}, File E55361
CSA	CSA Component Acceptance Notice #5, File CA 88324
IEC/EN/DIN EN 60747-5-5	Maximum Working Insulation Voltage V_{IORM} = 1414 V_{peak}

Insulation Characteristics

Table 3 IEC/EN/DIN EN 60747-5-5 Insulation Characteristics

Description	Symbol	Characteristic	Unit
Installation classification per DIN VDE 0110/39, Table 1 for rated mains voltage ≤ 600 V_{RMS} for rated mains voltage ≤ 1000 V_{RMS}		 I – IV I – III	
Climatic Classification		40/110/21	
Pollution Degree (DIN VDE 0110/39)		2	
Maximum Working Insulation Voltage	V_{IORM}	1414	V_{peak}
Input to Output Test Voltage, Method b (see Note 1) V_{IORM} x 1.875=V_{PR}, 100% Production Test with t_m=1 sec, Partial discharge < 5 pC	V_{PR}	2652	V_{peak}
Input to Output Test Voltage, Method a (see Note 1) V_{IORM} × 1.6=V_{PR}, Type and Sample Test, t_m=10 sec, Partial discharge < 5 pC	V_{PR}	2262	V_{peak}
Highest Allowable Overvoltage (see Note 1) (Transient Overvoltage tini = 60 sec)	V_{IOTM}	8000	V_{peak}
Safety-limiting values – maximum values allowed in the event of a failure (see Note 2). Case Temperature Input Current Output Power	 T_S $I_{S, INPUT}$ $P_{S, OUTPUT}$	 175 230 600	 °C mA mW
Insulation Resistance at T_S, V_{IO} = 500 V	R_S	$>10^9$	Ω

NOTE

1. Refer to IEC/EN/DIN EN 60747-5-5 Optoisolator Safety Standard section of the *Avago Regulatory Guide to Isolation Circuits*, AV02-2041EN for a detailed description of Method a and Method b partial discharge test profiles.
2. These optocouplers are suitable for "safe electrical isolation" only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits. Surface mount classification is Class A in accordance with CECC 00802.

Insulation and Safety-Related Specifications

Table 4 Insulation and Safety Related Specifications

Parameter	Symbol	ACNU-3410	Units	Conditions
Minimum External Air Gap (Clearance)	L(101)	10.5	mm	Measured from input terminals to output terminals, shortest distance through air.
Minimum External Tracking (Creepage)	L(102)	11.0	mm	Measured from input terminals to output terminals, shortest distance path along body.
Minimum Internal Plastic Gap (Internal Clearance)		0.5	mm	Through insulation distance conductor to conductor, usually the straight line distance thickness between the emitter and detector.
Tracking Resistance (Comparative Tracking Index)	CTI	> 300	V	DIN IEC 112/VDE 0303 Part 1
Isolation Group		IIIa		Material Group (DIN VDE 0110, 1/89, Table 1)

NOTE All Avago data sheets report the creepage and clearance inherent to the optocoupler component itself. These dimensions are needed as a starting point for the equipment designer when determining the circuit insulation requirements. However, once mounted on a printed circuit board, minimum creepage and clearance requirements must be met as specified for individual equipment standards. For creepage, the shortest distance path along the surface of a printed circuit board between the solder fillets of the input and output leads must be considered (the recommended Land Pattern does not necessarily meet the minimum creepage of the device). There are recommended techniques, such as grooves and ribs, that may be used on a printed circuit board to achieve desired creepage and clearances. Creepage and clearance distances will also change depending on factors, such as pollution degree and insulation level.

Absolute Maximum Ratings

Table 5 Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units	Note
Storage Temperature	T_S	–55	125	°C	
Operating Temperature	T_A	–40	110	°C	
Average Input Current	$I_{F(AVG)}$		25	mA	a
Peak Transient Input Current (<1 ms pulse width, 300pps)	$I_{F(TRAN)}$		1	A	
Reverse Input Voltage	V_R		5	V	
"High" Peak Output Current	$I_{OH(PEAK)}$		3.0	A	b
"Low" Peak Output Current	$I_{OL(PEAK)}$		3.0	A	b
Total Output Supply Voltage	$(V_{DD} – V_{SS})$	–0.5	35	V	
Negative Output Supply Voltage	$(V_E – V_{SS})$	–0.5	15	V	
Positive Output Supply Voltage	$(V_{DD} – V_E)$	–0.5	$35 – (V_E – V_{SS})$	V	
Output Voltage	$V_{O(PEAK)}$	–0.5	V_{DD}	V	
Output IC Power Dissipation	P_O		500	mW	c
Total Power Dissipation	P_T		550	mW	d

a. Derate linearly above 70°C free-air temperature at a rate of 0.3 mA/°C.

b. Maximum pulse width = 10 µs. This value is intended to allow for component tolerances for designs with I_O peak minimum = 2.5A. See the Applications section for additional details on limiting I_{OH} peak.

c. Derate linearly above 85°C free-air temperature at a rate of12.5 mW/°C.

d. Derate linearly above 85°C free-air temperature at a rate of 13.75 mW/°C. The maximum LED junction temperature should not exceed 125°C.

Recommended Operating Conditions

Table 6 Recommended Operating Conditions

Parameter	Symbol	Min	Max.	Units	Note
Operating Temperature	T_A	–40	110	°C	
Output Supply Voltage	$(V_{DD} – V_{SS})$	15	30	V	
Negative Output Supply Voltage	$(V_E – V_{SS})$	0	15	V	
Positive Output Supply Voltage	$(V_{DD} – V_E)$	15	$30 – (V_E – V_{SS})$	V	
Input Current (ON)	$I_{F(ON)}$	7	12	mA	
Input Voltage (OFF)	$V_{F(OFF)}$	–3.6	0.5	V	

Electrical Specifications (DC)

All typical values are at T_A = 25°C, $V_{DD} - V_E$ = 15V, $V_E - V_{SS}$ = 15V. All minimum and maximum specifications are at recommended operating conditions (T_A = –40°C to 110°C, $I_{F(ON)}$ = 7 mA to 12 mA, $V_{F(OFF)}$ = –3.6V to 0.5V, $V_{DD} - V_E$ = 15V, $V_E - V_{SS}$ = 15V), unless otherwise noted.

Table 7 Electrical Specifications (DC)

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Note
High Level Peak Output Current	I_{OH}	–2.5			A	$V_{DD} - V_O$ = 15		a
Low Level Peak Output Current	I_{OL}	2.5			A	$V_O - V_{SS}$ =15		a
High Output Transistor RDS(ON)	$R_{DS,OH}$	0.5	1.5	3.0	Ω	I_{OH} = 4 A		b
Low Output Transistor RDS(ON)	$R_{DS,OL}$	0.2	0.9	1.8	Ω	I_{OL} = –4 A		b
High Level Output Voltage	V_{OH}	V_{DD} – 0.3	V_{DD} – 0.12		V	I_O = –100 mA		c, d
High Level Output Voltage	V_{OH}		V_{DD}		V	I_O = 0 mA , I_F = 10 mA		
Low Level Output Voltage	V_{OL}		0.05	0.25	V	I_O = 100 mA		
High Level Output Supply Current (V_{DD})	I_{DDH}		3	5	mA	I_F = 10 mA		
Low Level Output Supply Current (V_{DD})	I_{DDL}		3	5	mA	V_F = 0V		
V_E High Level Output Supply Current	I_{EH}	–1.3	–0.9		mA	I_F = 10 mA		
V_E Low Level Output Supply Current	I_{EL}	–1.0	–0.7		mA	V_F = 0V		
Threshold Input Current Low to High	I_{FLH}	0.50	2.5	6	mA	V_O > 5V		
Threshold Input Voltage High to Low	V_{FHL}	0.5			V			
Input Forward Voltage	V_F	1.20	1.45	1.85	V	I_F = 10 mA		
Temperature Coefficient of Input Forward Voltage	$\Delta V_F/\Delta T_A$		–1.5		mV/°C	I_F = 10 mA		
Input Reverse Breakdown Voltage	BV_R	5			V	I_R = 100 mA		
Input Capacitance	C_{IN}		23		pF	f = 1 MHz, V_F = 0V		
UVLO Threshold	V_{UVLO+}	11.9	12.6	13.2	V	V_O > 5V, I_F = 10 mA		
	V_{UVLO-}	10.9	11.6	12.2				
UVLO Hysteresis	$UVLO_{HYS}$		1.0		V			

a. Maximum pulse width = 10 ms.

b. Output is sourced at –2.5 A/2.5 A with a maximum pulse width = 10 µs.

c. In this test, V_{OH} is measured with a DC load current. When driving capacitive loads, V_{OH} will approach V_{DD} as I_{OH} approaches zero amps.

d. Maximum pulse width = 1 ms.

Switching Specifications (AC)

All typical values are at T_A = 25°C, $V_{DD} - V_E$ = 15V, $V_E - V_{SS}$ = 15V. All minimum and maximum specifications are at recommended operating conditions (T_A = –40°C to 110°C, $I_{F(ON)}$ = 7 mA to 12 mA, $V_{F(OFF)}$ = –3.6V to 0.5V, $V_{DD} - V_E$ = 15V, $V_E - V_{SS}$ = 15V), unless otherwise noted.

Table 8 Switching Specifications (AC)

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Note
Propagation Delay Time to High Output Level	t_{PLH}	50	75	150	ns	R_G = 10Ω, C_G = 25 nF, f = 10 kHz, Duty Cycle = 50%, I_F = 10 mA,	3	
Propagation Delay Time to Low Output Level	t_{PHL}	50	70	150	ns			
Pulse Width Distortion	PWD			80	ns		3	a
Propagation Delay Difference Between Any Two Parts	PDD ($t_{PHL} - t_{PLH}$)	–90		90	ns		3	b
Propagation Delay Skew	t_{PSK}			80	ns		3	c
Rise Time	t_R		20	50	ns		3	
Fall Time	t_F		10	30	ns			
Output High Level Common Mode Transient Immunity	$\|CM_H\|$	100			kV/µs	T_A = 25°C, I_F = 10 mA, V_{CM} = 1500 V,	4	d, e
Output Low Level Common Mode Transient Immunity	$\|CM_L\|$	100			kV/µ	T_A = 25°C, V_F = 0 V, V_{CM} = 1500 V		d, f

a. Pulse Width Distortion (PWD) is defined as $|t_{PHL} - t_{PLH}|$ for any given device.

b. The difference between t_{PH}L and t_{PLH} between any two ACNU-3410 parts under the same test condition.

c. t_{PSK} is equal to the worst case difference in t_{PHL} or t_{PLH} that will be seen between units at any given temperature and specified test conditions.

d. Pin 1 and 4 need to be connected to LED common. Split resistor network in the ratio 1:1.5 with 150 Ω at the anode and 200 Ω at the cathode.

e. Common mode transient immunity in the high state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM}, to assure that the output will remain in the high state (i.e., V_O > 15.0 V).

f. Common mode transient immunity in a low state is the maximum tolerable dV_{CM}/dt of the common mode pulse, V_{CM}, to assure that the output will remain in a low state (i.e., V_O < 1.0 V).

Package Characteristics

All typical values are at T_A = 25°C. All minimum/maximum specifications are at recommended operating conditions, unless otherwise noted.

Table 9 Package Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Note
Input-Output Momentary Withstand Voltage	V_{ISO}	5000			V_{RMS}	RH < 50%, t = 1 min., T_A = 25°C		a, b
Input-Output Resistance	R_{I-O}		10^{12}		Ω	V_{I-O} = 500 V_{DC}		b
Input-Output Capacitance	C_{I-O}		0.5		pF	f =1 MHz		

a. In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage ≥ 6000 V_{RMS} for 1 second (leakage detection current limit, I_{I-O} ≤ 5 µA).

b. The device is considered to be a two-terminal device: pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7, and 8 shorted together.

Figure 3 t_{PLH}, t_{PHL}, PWD PDD, t_{PSK}, t_r, and t_f Test Circuit and Waveforms

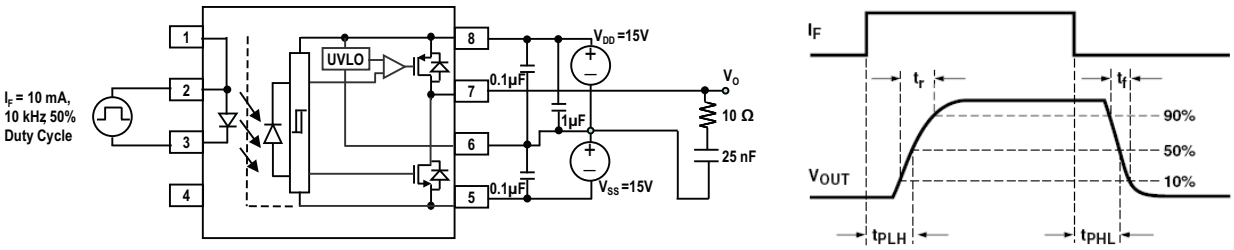
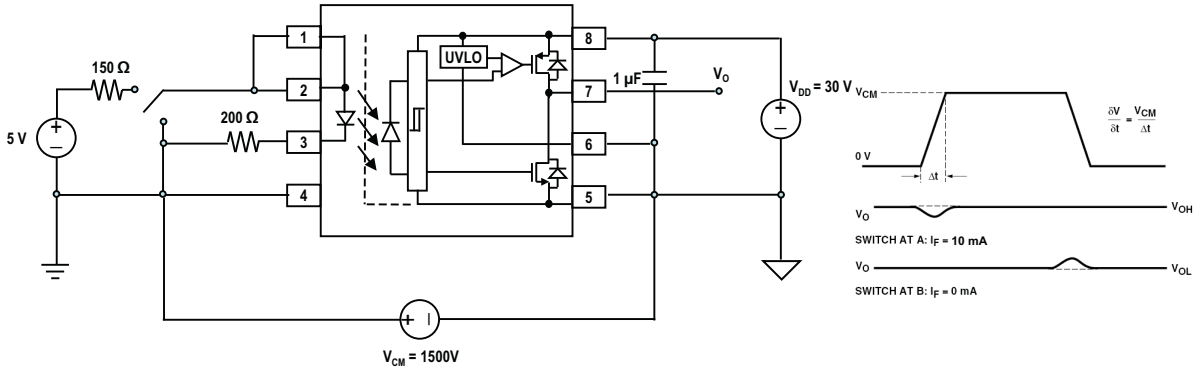


Figure 4 CMR Test Circuit with Split Resistors Network and Waveforms



Application Information

Product Overview Description

The ACNU-3410 is an optically isolated power output stage capable of driving IGBT or power MOSFET. Based on BCDMOS technology, this gate drive optocoupler delivers higher peak output current, better rail-to-rail output voltage performance and faster speed than the previous generation products.

The high peak output current and short propagation delay are needed for fast IGBT switching to reduce dead time and improve system overall efficiency. Rail-to-rail output voltage ensures that the MOSFET's gate voltage is driven to the optimum intended level with no power loss across the MOSFET. This helps the designer lower the system power, which is suitable for bootstrap power supply operation.

The ACNU-3410 has a V_E pin that allows of use negative power supply without affecting the UVLO monitoring the positive power supply. It has very high CMR (common mode rejection) rating which allows the microcontroller and the MOSFET to operate at very large common mode noise found in industrial motor drives and other power switching applications. The input is driven by direct LED current and has a hysteresis that prevents output oscillation if insufficient LED driving current is applied. This will eliminates the need of additional Schmitt trigger circuit at the input LED.

Recommended Application Circuit

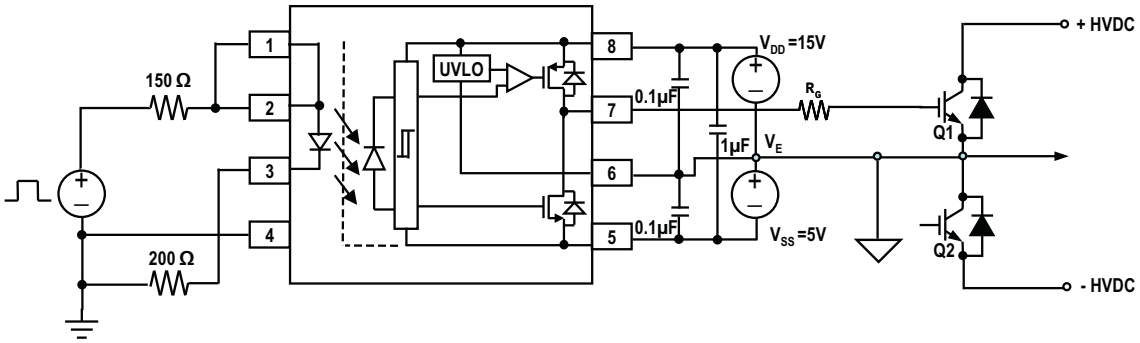
The recommended application circuit shown in Figure 5 illustrates a typical gate drive implementation using the ACNU-3410.

The supply bypass capacitors provide the large transient currents necessary during a switching transition. Because of the transient nature of the charging currents, a low current (5.0 mA) power supply will be enough to power the device. The split resistors (in the ratio of 1:1.5) across the LED will provide a high CMR response by providing a balanced resistance network across the LED. Connect pin 1 and pin 4 to LED common.

The gate resistor R_G serves to limit gate charge current and controls the IGBT switching times.

In PC board design, care should be taken to avoid routing the IGBT's collector or emitter traces close to the ACNU-3410 input as this can result in unwanted coupling of transient signals into ACNU-3410 and degrade performance.

Figure 5 Recommended Application Circuit with Split Resistors LED Drive

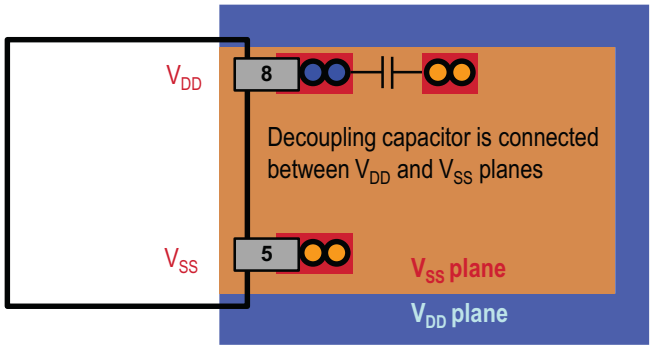


Recommended Supply and Ground Planes Layout

At 3A rated high current switching, decoupling capacitor must be close to V_{DD} and V_{SS} pins.

And due to the fast switching, large V_{DD} and V_{SS} planes are recommended to prevent noise by lowering the parasitic inductance.

Figure 6 Recommended Supply and Ground Planes Layout



For product information and a complete list of distributors, please go to our web site: www.broadcom.com.

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